

Data sheet acquired from Harris Semiconductor SCHS183C

High-Speed CMOS Logic Octal D-Type Flip-Flop, 3-State Positive-Edge Triggered

February 1998 - Revised May 2004

Features

- · Buffered Inputs
- Common Three-State Output Enable Control
- Three-State Outputs
- . Bus Line Driving Capability
- Typical Propagation Delay (Clock to Q) = 15ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2-V to 6-V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5-V to 5.5-V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)

Description

The 'HC374, 'HCT374, 'HC574, and 'HCT574 are octal D-type flip-flops with 3-state outputs and the capability to drive 15 LSTTL loads. The eight edge-triggered flip-flops enter data into their registers on the LOW to HIGH transition of clock (CP). The output enable (\overline{OE}) controls the 3-state outputs and is independent of the register operation. When \overline{OE} is HIGH, the outputs are in the high-impedance state. The 374 and 574 are identical in function and differ only in their pinout arrangements.

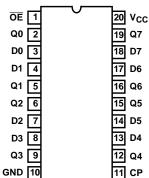
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC374F3A	-55 to 125	20 Ld CERDIP
CD54HC574F3A	-55 to 125	20 Ld CERDIP
CD54HCT374F3A	-55 to 125	20 Ld CERDIP
CD54HCT574F3A	-55 to 125	20 Ld CERDIP
CD74HC374E	-55 to 125	20 Ld PDIP
CD74HC374M	-55 to 125	20 Ld SOIC
CD74HC374M96	-55 to 125	20 Ld SOIC
CD74HC574E	-55 to 125	20 Ld PDIP
CD74HC574M	-55 to 125	20 Ld SOIC
CD74HC574M96	-55 to 125	20 Ld SOIC
CD74HCT374E	-55 to 125	20 Ld PDIP
CD74HCT374M	-55 to 125	20 Ld SOIC
CD74HCT374M96	-55 to 125	20 Ld SOIC
CD74HCT574E	-55 to 125	20 Ld PDIP
CD74HCT574M	-55 to 125	20 Ld SOIC
CD74HCT574M96	-55 to 125	20 Ld SOIC
CD74HCT574PWR	-55 to 125	20 Ld TSSOP

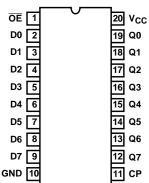
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel.

Pinouts

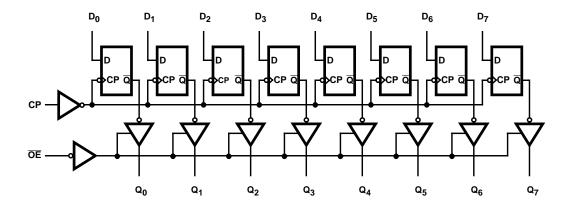
CD54HC374, CD54HCT374 (CERDIP) CD74HC374, CD74HCT374 (PDIP, SOIC) TOP VIEW



CD54HC574, CD54HCT574 (CERDIP) CD74HC574 (PDIP, SOIC) CD74HCT574 (PDIP, SOIC, TSSOP) TOP VIEW



Functional Diagram



TRUTH TABLE

	OUTPUT			
ŌĒ	СР	Dn	Qn	
L	\uparrow	Н	Н	
L	↑	L	L	
L	L	X	Q0	
Н	X	X	Z	

H = High Level (Steady State)

L = Low Level (Steady State)

X= Don't Care

↑= Transition from Low to High Level

Q0= The level of Q before the indicated steady-state input conditions were established

Z = High Impedance State

$\begin{tabular}{lll} \textbf{Absolute Maximum Ratings} \\ DC & Supply & Voltage, V_{CC} & -0.5V to 7V \\ DC & Input Diode Current, I_{IK} & $-0.5V$ or $V_I > V_{CC} + 0.5V$ & <math>\pm 20\text{mA}$ \\ DC & Output Diode Current, I_{OK} & $-0.5V$ or $V_O > V_{CC} + 0.5V$ & <math>\pm 20\text{mA}$ \\ DC & Drain Current, per Output, I_O & $\pm 20\text{mA}$ \\ DC & Drain Current, per Output, I_O & $\pm 35\text{mA}$ \\ DC & Output Source or Sink Current per Output Pin, I_O & $\pm 25\text{mA}$ \\ DC & V_{CC}$ or Ground Current, I_{CC} & $\pm 50\text{mA}$ \\ \hline \end{tabular}$

Temperature Range, T_A -55°C to 125°C

 2V
 1000ns (Max)

 4.5V
 500ns (Max)

 6V
 400ns (Max)

Thermal Information

Thermal Resistance (Typical, Note 1)θ _{JA} (^o	C/W)
E (PDIP) Package	69
M (SOIC) Package	58
PW (TSSOP) Package	83
Maximum Junction Temperature	50°C
Maximum Storage Temperature Range65°C to 1	50 ⁰ C
Maximum Lead Temperature (Soldering 10s)	00°C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating, and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

Supply Voltage Range, V_{CC}

Input Rise and Fall Time

		TES CONDI		V _{CC}		25°C		-40°C T	O 85°C	-55°C T	O 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES	IC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	i	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	•	-	3.15	-	3.15	-	V	
				6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
OWO Edda			-0.02	6	5.9	-	-	5.9	-	5.9	-	V	
High Level Output	1		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V	
112 20000			-7.8	6	5.48	-	-	5.34	-	5.2	-	V	
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
			0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output	1		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V	
			7.8	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	Ι _Ι	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА	

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ
Three- State Leakage Current	V _{IL} or V _{IH}	V _O =V _{CC} or GND	-	6	-	-	±0.5	-	±5.0	-	±10	μΑ
HCT TYPES	•						•					
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	l _l	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Three- State Leakage Current	V _{IL} or V _{IH}	V _O =V _{CC} or GND	-	6	-	-	±0.5	-	±5.0	-	±10	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

	UNIT LOADS							
INPUT	HCT374	HCT574						
D0 - D7	0.3	0.4						
СР	0.9	0.75						
ŌĒ	1.3	0.6						

NOTE: Unit Load is ΔI_{CC} limit specific in DC Electrical Specifications Table, e.g., 360 μ A max. at 25 o C.

^{2.} For dual-supply systems, theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Prerequisite for Switching Specifications

				25°C		-40	°C TO 8	5°C	-55 ^c	C TO 12	5°C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
HC TYPES	•											
Maximum Clock	f _{MAX}	2	6	-	-	5	-	-	4	-	-	MHz
Frequency		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz
Clock Pulse Width	t _W	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns
Setup Time	t _{SU}	2	60	-	-	75	-	-	90	-	-	ns
Data to Clock		4.5	12	-	-	15	-	-	18	-	-	ns
		6	10	-	-	13	-	-	15	-	-	ns
Hold Time	t _H	2	5	-	-	5	-	-	5	-	-	ns
Data to Clock		4.5	5	-	-	5	-	-	5	-	-	ns
		6	5	-	-	5	-	-	5	-	-	ns
HCT TYPES	•	•		•			•			•		
Maximum Clock Frequency	fMAX	4.5	30	-	-	25	-	-	20	-	-	MHz
Clock Pulse Width	t _W	4.5	16	-	-	20	-	-	24	-	-	ns
Setup Time Data to Clock	t _{SU}	4.5	12	-	-	15	-	-	18	-	-	ns
Hold Time Data to Clock	t _H	4.5	5	-	-	5	-	-	5	-	-	ns

Switching Specifications $C_L = 50 pF$, Input t_f , $t_f = 6 ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay Clock to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	165	-	205	-	250	ns
			4.5	-	-	33	-	41	-	50	ns
		C _L = 15pF	5	1	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	28	-	35	-	43	ns
Output Disable to Q	t _{PLZ} , t _{PHZ}	C _L = 50pF	2	-	-	135	-	170	-	205	ns
			4.5	1	-	27	-	34	-	41	ns
		C _L = 15pF	5	-	11	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	23	-	29	-	35	ns

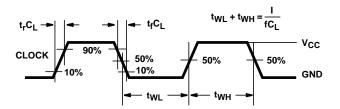
Switching Specifications $C_L = 50pF$, Input t_r , $t_f = 6ns$ (Continued)

		TEST		25°C			С ТО °С	-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Enable to Q	t _{PZL} , t _{PZH}	C _L = 50pF	2	-	-	150	-	190	-	225	ns
			4.5	-	-	30	-	38	-	45	ns
		C _L = 15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	-	60	-	-	-	-	-	MHz
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
			6	-	-	10	-	13	-	15	ns
Input Capacitance	Cl	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	CO	-	-	20	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L = 15pF	5	-	39	-	-	-	-	-	pF
HCT TYPES					•						
Propagation Delay	t _{PHL} , t _{PLH}										
Clock to Output		C _L = 50pF	4.5	-	-	33	-	41	-	50	ns
		C _L = 15pF	5	-	15	-	-	-	-	-	ns
Output Disable to Q	t _{PLZ} , t _{PHZ}	$C_L = 50pF$	4.5	-	-	28	-	35	-	42	ns
		$C_L = 15pF$	5	-	11	-	-	-	-	-	ns
Output Enable to Q	t _{PZL} , t _{PZH}	$C_L = 50pF$	4.5	-	-	30	-	38	-	45	ns
		C _L = 15pF	5	-	12	-	-	-	-	-	ns
Maximum Clock Frequency	f _{MAX}	C _L = 15pF	5	-	60	-	-	-	-	-	MHz
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	12	-	15	-	18	ns
Input Capacitance	Cl	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Three-State Output Capacitance	c _o	-	-	20	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L = 15pF	5	-	47	-	-	-	-	-	pF

^{3.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per package.

^{4.} P_D = C_{PD} V_{CC}² f_i + Σ V_{CC}² f_O C_L where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

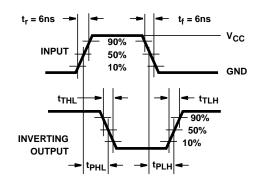


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

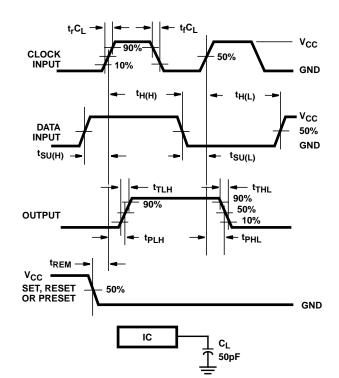
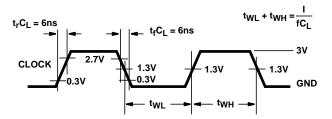


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

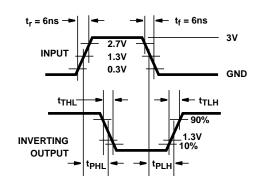


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

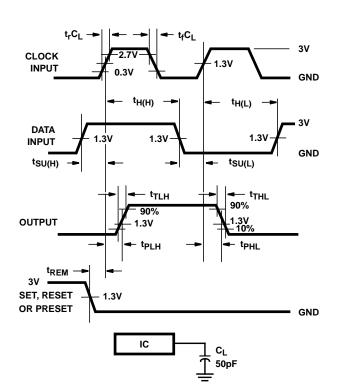
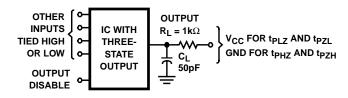


FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

Test Circuits and Waveforms (Continued) 6ns 3V V_{CC} OUTPUT OUTPUT 90% **DISABLE** 50% DISABLE 10% 0.3 GND GND t_{PZL} → - t_{PLZ} → t_{PZL} ► t_{PLZ} → **OUTPUT LOW** OUTPUT LOW 50% TO OFF TO OFF 1.3V 10% 10% ◆ t_{PHZ} ◆ - t_{PZH} · t_{PHZ} → tpzh -90% 90% **OUTPUT HIGH OUTPUT HIGH** 50% TO OFF TO OFF 1.3V OUTPUTS **OUTPUTS OUTPUTS OUTPUTS OUTPUTS OUTPUTS ENABLED** ENABLED **DISABLED ENABLED** DISABLED

FIGURE 7. HC THREE-STATE PROPAGATION DELAY **WAVEFORM**

FIGURE 8. HCT THREE-STATE PROPAGATION DELAY **WAVEFORM**



ENABLED

NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 9. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-8974201RA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC374F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC574F	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC574F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT374F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT574F	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT574F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC574EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC574M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC574MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						no Sb/Br)		
CD74HCT374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT574EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT574M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT574PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

9-Oct-2007

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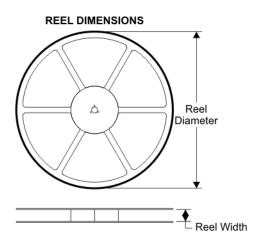
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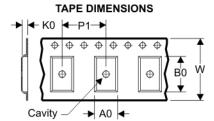




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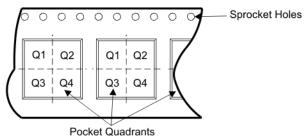
TAPE AND REEL BOX INFORMATION





	40	Dimension designed to accommodate the component width
Œ	30	Dimension designed to accommodate the component length
F	(0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
П	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC374M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
CD74HC574M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
CD74HCT374M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
CD74HCT574M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
CD74HCT574PWR	PW	20	SITE 41	330	16	6.95	7.1	1.6	8	16	Q1





Device	Package	Pins Site		Length (mm)	Width (mm)	Height (mm)	
CD74HC374M96	DW	20	SITE 41	346.0	346.0	41.0	
CD74HC574M96	DW	20	SITE 41	346.0	346.0	41.0	
CD74HCT374M96	DW	20	SITE 41	346.0	346.0	41.0	
CD74HCT574M96	DW	20	SITE 41	346.0	346.0	41.0	
CD74HCT574PWR	PW	20	SITE 41	346.0	346.0	33.0	

14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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